Transistor PNP, TO-19







Pin Configuration

- 1. Emitter
- 2. Base
- 3. Collector

Features:

- PNP Silicon Planar Switching Transistor
- · Fast switching devices exhibiting short turn-off and low saturation voltage characteristics
- Switching And Linear Application DC to VHF Amplifier Applications

Absolute Maximum Ratings:

Parameter	Symbol	Value	Unit	
Collector-Emitter Voltage	V _{CEO}	60		
Collector-Base Voltage	V _{CBO}	60	V	
Emitter-Base Voltage	V _{EBO}	5		
Collector Current Continuous	I _C	600	mA	
Power Dissipation at T _a = 25°C Derate above 25°C	Б	600 3.43	mW mW/°C	
Power Dissipation at T _c = 25°C Derate above 25°C	- P _D	3 17.2	W mW/°C	
Operating and Storage Junction Temperature Range	T _j , T _{stg}	-65 to +200	°C	

Transistor PNP, TO-19



Electrical Characteristics: $(T_a = +25^{\circ}C \text{ unless otherwise specified})$

Boromotor	Symbol	To at O an dition	Value		Unit	
Parameter	Parameter Symbol Test Condition		Min.	Max.	Unit	
Collector-Emitter Voltage	V _{CEO} *	I _C = 10mA, I _B = 0	00	-		
Collector-Base Voltage	V _{CBO}	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm E} = 0$	60	-	٧	
Emitter-Base Voltage	V _{EBO}	$I_{E} = 10\mu A, I_{C} = 0$	5	-		
Collector-Cut off Current	I _{CBO}	$V_{CB} = 50V, I_{E} = 0$ $T_{A} = 150^{\circ}C \ V_{CB} = 50V, I_{E} = 0$ $V_{CE} = 30V, V_{BE} = 0.5V$	-	10 10 50	nΑ μΑ nΑ	
Base Current	I _B	V _{CE} = 30V, V _{BE} = 0.5V	-	50	nA	
Collector Emitter Saturation Voltage	V _{CE(sat)} *	I _C = 150mA, I _B = 15mA	-	0.4		
Base Emitter Saturation Voltage	V _{BE(sat)} *	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA	-	1.3 2.6	V	
DC Current Gain	h _{FE}	$I_{C} = 0.1 \text{mA}, V_{CE} = 10 \text{V}$ $I_{C} = 1 \text{mA}, V_{CE} = 10 \text{V}$ $I_{C} = 10 \text{mA}, V_{CE} = 10 \text{V}$ $I_{C} = 150 \text{mA}, V_{CE} = 10 \text{V}^{*}$ $I_{C} = 500 \text{mA}, V_{CE} = 10 \text{V}^{*}$	>75 >100 >100 100 - 300 >50	-	-	
Dynamic Characteristics	•					
Transition Frequency	ft**	I _C = 50mA, V _{CE} = 20V, f = 100MHz	200	-	MHz	
Output Capacitance	C _{ob}	V _{CB} = 10V, I _E = 0, f = 100kHz	-	8	pF	
Input Capacitance	C _{ib}	$V_{BE} = 2V, I_{C} = 0, f = 100kHz$	-	30		
Switching Time						
Delay Time	t _d	I _C = 150mA, I _{B1} = 15mA	-	10		
Rise Time	t _r	V _{CC} = 30V	-	40]	
Turn-on Time	t _{on}	-	-	45	ns	
Storage time	t _s	I _C = 150mA, I _{B1} = I _{B2} = 15mA	-	80]	
Fall Time	t _f	V _{CC} = 6V	-	30	_	
Turn-off Time	1 t	1 -	_	100		

Pulse Test: Pulse Width = $300\mu s$, Duty Cycle = 2%.

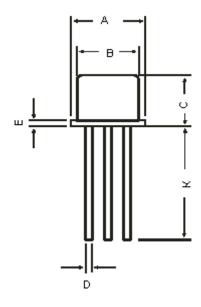


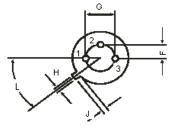
^{**} ft is defined as the frequency at which /hfe/ extrapolates to unity.

Transistor PNP, TO-19



TO-39 Metal Can Package





Dimensions	Min.	Max.
Α	8.5	9.39
В	7.74	8.5
С	6.09	6.6
D	0.4	0.53
E	-	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
K	12.7	-
L	42°	48°

Dimensions : Millimetres

Pin Configuration

- 1. Emitter
- 2. Base
- 3. Collector

Part Number Table

Description	Part Number		
Transistor, PNP, TO-39	2N2905A		

Important Notice: This data sheet and its contents (the "Information") belong to the members of the Premier Farnell group of companies (the "Group") or are licensed to it. No licence is granted for the use of it other than for information purposes in connection with the products to which it relates. No licence of any intellectual property rights is granted. The Information is subject to change without notice and replaces all data sheets previously supplied. The Information supplied is believed to be accurate but the Group assumes no responsibility for its accuracy or completeness, any error in or omission from it or for any use made of it. Users of this data sheet should check for themselves the Information and the suitability of products for their purpose and not make any assumptions based on information included or omitted. Liability for loss or damage resulting from any reliance on the Information or use of it (including liability resulting from negligence or where the Group was aware of the possibility of such loss or damage arising) is excluded. This will not operate to limit or restrict the Group's liability for death or personal injury resulting from its negligence. Multicomp is the registered trademark of the Group. © Premier Farnell plc 2012.

www.element14.com www.farnell.com www.newark.com

